

# New Jersey Semi-Conductor Products, Inc.

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## 2N2917 • 2N2918 • 2N2976 • 2N2977 NPN LOW-LEVEL, LOW-NOISE DIFFERENTIAL AMPLIFIERS

- BETA RATIO . . . . .  $\frac{h_{FE1}}{h_{FE2}} = 20\% \text{ (MAX) AT } 100 \mu\text{A}$
- V<sub>BE</sub> MATCH . . . . .  $|V_{BE1}-V_{BE2}| = 5.0 \text{ mV (MAX) AT } 100 \mu\text{A}$   
 $|V_{BE1}-V_{BE2}| = 10 \text{ mV (MAX) FROM } 10 \mu\text{A TO } 1.0 \text{ mA}$
- V<sub>BE</sub> TRACKING . . . . .  $\Delta V_{BE} = 20 \mu\text{V}/^\circ\text{C (MAX) AT } 100 \mu\text{A}$
- BREAKDOWN VOLTAGE . . . . .  $V_{CEO} = 45 \text{ V (MIN)}$
- LOW NOISE . . . . .  $NF = 3.0 \text{ dB (MAX) WIDE BAND AND AT } 1.0 \text{ kHz}$

### ABSOLUTE MAXIMUM RATINGS (Note 1)

#### Maximum Temperatures

Storage Temperature	-65°C to +200°C			
Operating Junction Temperature	200°C Maximum			
Lead Temperature (Soldering, 60 second time limit)	300°C Maximum			

### Maximum Power Dissipation (Notes 2 and 3)

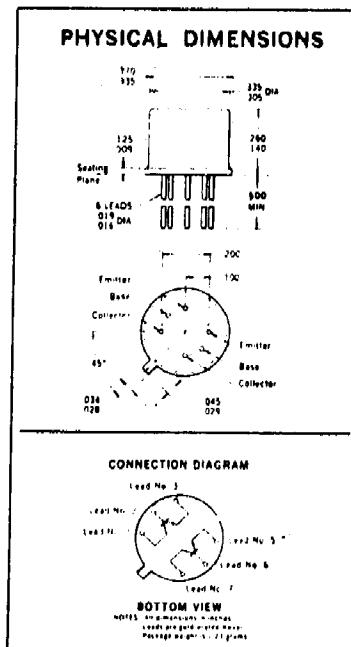
	2N2917	2N2917	2N2976	2N2976
	2N2918	2N2918	2N2977	2N2977
ONE SIDE	BOTH SIDES	ONE SIDE	BOTH SIDES	
0.75 Watt	1.5 Watts	0.5 Watt	0.75 Watt	
0.43 Watt	0.86 Watt	0.29 Watt	0.43 Watt	
0.3 Watt	0.6 Watt	0.25 Watt	0.30 Watt	

### Maximum Voltages and Current for Each Transistor

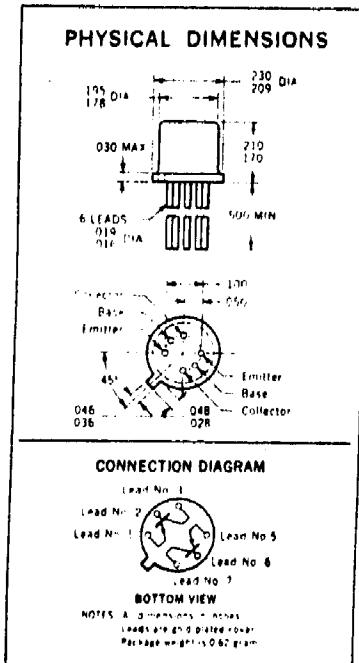
V <sub>CBO</sub>	Collector to Base Voltage	45 Volts
V <sub>CEO</sub>	Collector to Emitter Voltage (Note 4)	45 Volts
V <sub>EBO</sub>	Emitter to Base Voltage	6.0 Volts
I <sub>c</sub>	Collector Current	30 mA

### MATCHING AND ELECTRICAL CHARACTERISTICS (25°C Free Air Temperature unless otherwise noted)

SYMBOL	CHARACTERISTICS	2N2917		2N2918		TEST CONDITIONS
		MIN.	MAX.	MIN.	MAX.	
$h_{FE1}$	DC Current Gain Ratio (Note 5)	0.8	1.0	0.8	1.0	$I_C = 100 \mu\text{A}$ $V_{CE} = 5.0 \text{ V}$
$h_{FE2}$						
$ V_{BE1}-V_{BE2} $	Base-Emitter Voltage Differential (Note 6)	10		10	$\text{mV}$	$I_C = 10 \mu\text{A}$ $V_{CE} = 5.0 \text{ V}$ to 1.0 mA
$ V_{BE1}-V_{BE2} $						
$(\Delta V_{BE1}-V_{BE2})$	Base-Emitter Voltage Differential Change ( $T_A = -55^\circ\text{C}$ to $+25^\circ\text{C}$ )	5.0		5.0	$\text{mV}$	$I_C = 100 \mu\text{A}$ $V_{CE} = 5.0 \text{ V}$
$(\Delta V_{BE1}-V_{BE2})$						
$(\Delta V_{BE1}-V_{BE2})$	Base-Emitter Voltage Differential Change ( $T_A = +25^\circ\text{C}$ to $+125^\circ\text{C}$ )	1.6		1.6	$\text{mV}$	$I_C = 100 \mu\text{A}$ $V_{CE} = 5.0 \text{ V}$
$(\Delta V_{BE1}-V_{BE2})$						
NF	Narrow Band Noise Figure ( $f = 1.0 \text{ kHz}$ )	2.0		2.0	$\text{mV}$	$I_C = 100 \mu\text{A}$ $V_{CE} = 5.0 \text{ V}$
NF						
NF	Wide Band Noise Figure ( $f = 15.7 \text{ kHz}$ )	4.0		3.0	$\text{dB}$	$I_C = 10 \mu\text{A}$ $V_{CE} = 5.0 \text{ V}$ $BW = 200 \text{ Hz}$ $R_S = 10 \text{ k}\Omega$ 3 dB pts @ 25 Hz & 10 kHz $R_S = 10 \text{ k}\Omega$
NF						



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ELECTRICAL CHARACTERISTICS (25°C Free Air Temperature unless otherwise noted)

SYMBOL	CHARACTERISTICS	MIN.	MAX.	UNITS	TEST CONDITIONS
$h_{FE}$	DC Current Gain	150			$I_C = 1.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}$
$h_{FE}$	DC Current Gain	100			$I_C = 100 \mu\text{A}$ $V_{CE} = 5.0 \text{ V}$
$h_{FE}$	DC Current Gain	60			$I_C = 10 \mu\text{A}$ $V_{CE} = 5.0 \text{ V}$
$h_{FE}(-55^\circ\text{C})$	DC Current Gain	15			$I_C = 10 \mu\text{A}$ $V_{CE} = 5.0 \text{ V}$
$V_{CE(\text{sat})}$	Collector Saturation Voltage		0.35	Volts	$I_C = 1.0 \text{ mA}$ $I_B = 0.1 \text{ mA}$
$V_{BE(\text{on})}$	Emitter-Base On Voltage		0.7	Volts	$I_C = 0.1 \text{ mA}$ $V_{CE} = 5.0 \text{ V}$
$I_{CBO}$	Collector Cutoff Current		10	nA	$I_E = 0$ $V_{CB} = 45 \text{ V}$
$I_{CBO}(150^\circ\text{C})$	Collector Cutoff Current		10	$\mu\text{A}$	$I_E = 0$ $V_{CB} = 45 \text{ V}$
$I_{CEO}$	Collector Cutoff Current		2.0	nA	$I_B = 0$ $V_{CE} = 5.0 \text{ V}$
$I_{EBO}$	Emitter Cutoff Current		2.0	nA	$I_C = 0$ $V_{EB} = 5.0 \text{ V}$
$C_{obo}$	Output Capacitance		6.0	pF	$I_E = 0$ $V_{CB} = 5.0 \text{ V}$
$h_{fe}$	High Frequency Current Gain ( $f = 20 \text{ MHz}$ )	3.0			$I_C = 0.5 \text{ mA}$ $V_{CE} = 5.0 \text{ V}$
$h_{ib}$	Input Resistance ( $f = 1 \text{ kHz}$ )	25	32	$\Omega$	$I_C = 1.0 \text{ mA}$ $V_{CB} = 5.0 \text{ V}$
$h_{ob}$	Output Conductance ( $f = 1 \text{ kHz}$ )		1.0	$\mu\text{mhos}$	$I_C = 1.0 \text{ mA}$ $V_{CB} = 5.0 \text{ V}$
$BV_{CBO}$	Collector to Base Breakdown Voltage	45		Volts	$I_C = 10 \mu\text{A}$ $I_E = 0$
$V_{CEO(\text{sust})}$	Collector to Emitter Sustaining Voltage (pulsed, notes 4 and 7)	45		Volts	$I_C = 10 \text{ mA}$ $I_B = 0$
$BV_{EBO}$	Emitter to Base Breakdown Voltage	6.0		Volts	$I_E = 10 \mu\text{A}$ $I_C = 0$